NSN 5961-01-531-2923

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-531-2923 **Inclosure Material:** Glass **Overall Length:** Between 0.030 inches and 0.035 inches **Terminal Length:** Between 0.160 inches and 0.190 inches **Overall Height:** Between 0.010 inches and 0.014 inches **Overall Width:** Between 0.030 inches and 0.035 inches **End Application:** Aews **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 100.00 nanoamperes collector current, dc peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0